Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC3422

Audio Frequency Power Amplifier Low-Speed Switching

- Suitable for the output stage of 5-watt car radios and car stereos.
- Good hfe linearity
- Complementary to 2SA1359.

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	40	V	
Collector-emitter voltage		V _{CEO}	40	V	
Emitter-base voltage		V _{EBO}	5	V	
Collector current		IC	3	Α	
Base current		ΙΒ	1	Α	
Collector power dissipation	Ta = 25°C	Pc	1.5	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

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5.8

93.1±0.1

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1.9MAX.
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Weight: 0.82 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

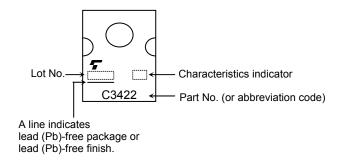
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

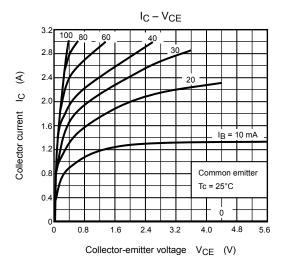
Electrical Characteristics (Tc = 25°C)

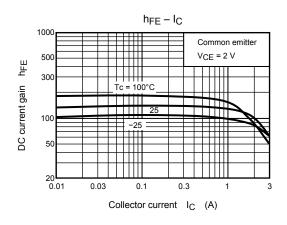
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 40 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	40	_	_	٧
DC current gain	h _{FE (1)} (Note)	V _{CE} = 2 V, I _C = 0.5 A	80	_	240	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 2.5 A	25	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 2 A, I _B = 0.2 A	_	_	0.8	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 0.5 A	_	_	1.0	٧
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	35	_	pF

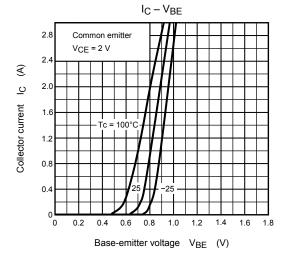
Note: h_{FE} (1) classification O: 80 to 160, Y: 120 to 240

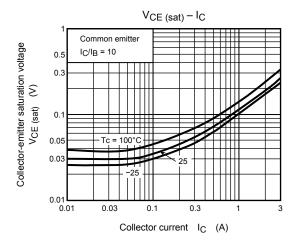
Marking

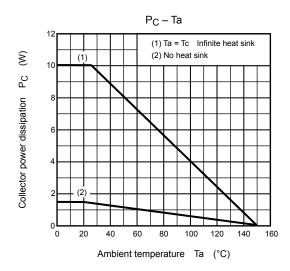


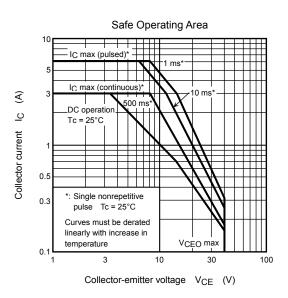












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20070701-EN

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